






 	<h2 style="color: #E67E22;">FQB9N50CTM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB9N50CTM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 500V 9A D2PAK
	Datenblätter:  FQB9N50CTM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 8437 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB9N50CTM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 500V 9A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	8437 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D²Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D²PAK (TO-263AB)
Verlustleistung (max)	135W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9A (Tc)
Rds On (Max) @ Id, Vgs	800 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	35nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1030pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)














































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Sie können auch interessiert sein:

 <p>FQB9N50CFTM_WS Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p>FQB9N50CFTM Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p>FQB9N50CFTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p>FQB9P25TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 250V 9.4A D2PAK</p>
 <p>FQB9N50CFTM_WS AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p>FQB9P25 FSC FSC TO-263</p>	 <p>FQB9N50TM Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p>FQB9N50CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>

heiße Teile

Mehr

 FQB6N70TM	 FQB6N90TM	 FQB6N90TM_AM002	 FQB6N90TM_AM002	 FQB7042FB
 FQB7045FB	 FQB70N03	 FQB70N06	 FQB70N08	 FQB70N10TM
 FQB7N10L	 FQB7N20L	 FQB7N60TM	 FQB7N60TM	 FQB7N65C
 FQB7N65CTM	 FQB7N65CTM	 FQB7P20TM	 FQB7P20TM	 FQB85N06
 FQB85N06TM	 FQB8N25TM	 FQB8N25TM	 FQB8N60C	 FQB8N60CFTM
 FQB8N60CFTM	 FQB8N60CTM	 FQB8N60CTM	 FQB8N60TM	 FQB8N90CTM
 FQB8N90CTM	 FQB8P10TM	 FQB8P10TM	 FQB8P10TM-NL	 FQB9N08L
 FQB9N08LTM	 FQB9N08LTM	 FQB9N25C	 FQB9N25CTM	 FQB9N25CTM
 FQB9N25TM	 FQB9N25TM	 FQB9N50C	 FQB9N50CFTM	 FQB9N50CFTM
 FQB9N50CTM	 FQB9N50TM	 FQB9N50TM	 FQB9P25TM	 FQB9P25TM

Contact us: Info@Y-IC.com

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